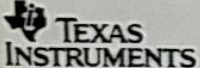



PCN Number:	20190606001.1		PCN Date:	June 7 2019																									
Title:	Qualification of additional Fab site (DMOS6) and Assembly site (CDAT) options for the BQ25910YFFR/T																												
Customer Contact:	PCN Manager		Dept:	Quality Services																									
Proposed 1st Ship Date:	Sept 7 2019		Estimated Sample Availability:	Date provided at sample request.																									
Change Type:																													
<input checked="" type="checkbox"/>	Assembly Site	<input type="checkbox"/>	Assembly Process	<input type="checkbox"/>	Assembly Materials																								
<input type="checkbox"/>	Design	<input type="checkbox"/>	Electrical Specification	<input type="checkbox"/>	Mechanical Specification																								
<input type="checkbox"/>	Test Site	<input type="checkbox"/>	Packing/Shipping/Labeling	<input type="checkbox"/>	Test Process																								
<input checked="" type="checkbox"/>	Wafer Bump Site	<input type="checkbox"/>	Wafer Bump Material	<input type="checkbox"/>	Wafer Bump Process																								
<input checked="" type="checkbox"/>	Wafer Fab Site	<input type="checkbox"/>	Wafer Fab Materials	<input type="checkbox"/>	Wafer Fab Process																								
		<input type="checkbox"/>	Part number change																										
PCN Details																													
Description of Change:																													
Texas Instruments is pleased to announce the qualification of an additional fab (DMOS6) and assembly (CDAT) site for the BQ25910YFFR/T.																													
<table border="1" style="width: 100%; border-collapse: collapse;"> <thead> <tr> <th colspan="4">Current Fab Site</th> <th colspan="4">Additional Fab Site</th> </tr> <tr> <th>Fab Site</th> <th>Process</th> <th>Bump Site</th> <th>Wafer Diameter</th> <th>Fab Site</th> <th>Process</th> <th>Bump Site</th> <th>Wafer Diameter</th> </tr> </thead> <tbody> <tr> <td>RFAB</td> <td>LBC9</td> <td>Clark-BP</td> <td>300 mm</td> <td>DMOS6</td> <td>LBC9</td> <td>CDAT-BP</td> <td>300 mm</td> </tr> </tbody> </table>						Current Fab Site				Additional Fab Site				Fab Site	Process	Bump Site	Wafer Diameter	Fab Site	Process	Bump Site	Wafer Diameter	RFAB	LBC9	Clark-BP	300 mm	DMOS6	LBC9	CDAT-BP	300 mm
Current Fab Site				Additional Fab Site																									
Fab Site	Process	Bump Site	Wafer Diameter	Fab Site	Process	Bump Site	Wafer Diameter																						
RFAB	LBC9	Clark-BP	300 mm	DMOS6	LBC9	CDAT-BP	300 mm																						
There are no material difference between devices currently manufactured and devices built with this manufacturing option.																													
Reason for Change:																													
Continuity of Supply																													
Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative):																													
None																													
Anticipated impact on Material Declaration																													
<input checked="" type="checkbox"/>	No Impact to the Material Declaration	<input type="checkbox"/>	Material Declarations or Product Content reports are driven from production data and will be available following the production release. Upon production release the revised reports can be obtained from the TI ECO website .																										
Changes to product identification resulting from this PCN:																													
Fab Site Information:																													
Chip Site		Chip Site Origin Code (20L)	Chip Site Country Code (21L)	Chip Site City																									
RFAB		RFB	USA	Richardson																									
DMOS6		DM6	USA	Dallas																									
Assembly Site Information:																													
Assembly Site	Assembly Site Origin (22L)	Assembly Country Code (21L)	Assembly City																										
TI Clark	QAB	PHL	Angeles City, Pampanga																										
CDAT	CDA	CHN	Chengdu																										
Sample product shipping label (not actual product label)																													



MADE IN: China
2DC: 2Q:

MSL 1 / 260C/UNLIM

OPT: ITEM: 73
LBL: 1A (L)T0:1168



(1P)PTAS2560YFFR
(Q) 3000 (D) 1710
(31T) LOT: 7133710JCP
(4W) SWR (1T) 2855550Z9A
(P)
(2P) REV: A0 (V) 0033317
(20L) CS0: DM6 (21L) CC0: USA
(22L) AS0: JCP (23L) AC0: CHN

Product Affected:

BQ25910YFFR	BQ25910YFFT
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TI Information
Selective Disclosure

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Type	Test Name / Condition	Duration	Qual Device: BQ25910YFF	QBS Product Reference: BQ25910YFF	QBS Product Reference: BQ25970YFF	QBS Product Reference: BQ25970YFFR	QBS Package Reference: BQ25970YFFR	QBS Package Reference: SN2600A0YZF
CLHTOL	Corner Lot Life Test FF, 125C	1000 Hours	-	-	-	-	-	1/45/0
CLHTOL	Corner Lot Life Test FS, 125C	1000 Hours	-	-	-	-	-	1/45/0
CLHTOL	Corner Lot Life Test SF, 125C	1000 Hours	-	-	-	-	-	1/45/0
CLHTOL	Corner Lot Life Test SS, 125C	1000 Hours	-	-	-	-	-	1/45/0
ED	Electrical Characterization	Per Datasheet Parameters	Pass	Pass	-	Pass	Pass	Pass
ELFR	Early Life Failure Rate, 125C	48 Hours	-	-	-	-	-	3/3000/0
ELFR	Early Life Failure Rate, 140C	24 Hours	-	-	1/800/0	-	-	-
HAST	Biased HAST, 130C/85%RH	96 Hours	-	3/231/0	3/231/0	-	-	3/231/0
HBM	ESD - HBM	3000 V	1/3/0	-	-	-	-	-
CDM	ESD - CDM	1600 V	1/3/0	1/3/0	-	1/3/0	1/3/0	-
HTOL	Life Test, 125C	1000 Hours	-	-	-	-	-	3/231/0
HTOL	Life Test, 140C	480 Hours	-	3/231/0	3/231/0	-	-	-
HTSL	High Temp. Storage Bake, 150C	1000 Hours	-	-	-	-	-	2/154/0
HTSL	High Temp. Storage Bake, 170C	420 Hours	-	3/231/0	3/231/0	-	-	-
LU	Latch-up	(per JESD78)	2/12/0	1/6/0	-	1/6/0	2/12/0	3/18/0
PD	Physical Dimensions	--	1/5/0	-	-	-	1/5/0	3/60/0
SBS	Bump-shear	--	1/50/0	-	3/150/0	-	1/50/0	3/15/0
SD	Surface Mount Solderability	Pb Free	1/22/0	-	-	-	1/25/0	3/15/0
SD	Surface Mount Solderability	Pb	1/22/0	-	-	-	1/25/0	-
TC	Temperature Cycle, -40 /85C	1039 Cycles	-	-	-	-	-	3/99/0
TC	Temperature Cycle, -55/125C	700 Cycles	-	3/231/0	3/231/0	-	-	3/231/0
UHASt	Unbiased HAST, 130C/85%RH	96 Hours	-	3/231/0	3/231/0	-	-	3/231/0

- QBS: Qual By Similarity
 - Qual Device BQ25910YFF is qualified at LEVEL1-260C
 - Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
 - The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
 - The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours
 - The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles
 Quality and Environmental data is available at TI's external Web site: <http://www.ti.com/>
Green/Pb-free Status:
 Qualified Pb-Free(SMT) and Green



Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Type	Test Name / Condition	Duration	Qual Device: TBQ25910YFFR
ED	Electrical Characterization	Per Datasheet Parameters	Pass
ELFR	Early Life Failure Rate, 140C	24 Hours	3/2400/0
HAST	Biased HAST, 130C/85%RH	96 Hours	3/231/0
HAST	Unbiased HAST, 130C/85%RH	96 Hours	3/231/0
HBM	ESD - HBM	3000 V	3/9/0
CDM	ESD - CDM	1500 V	3/9/0
HTOL	Life Test, 140C	480 Hours	3/231/0
HTSL	High Temp. Storage Bake, 170C	420 Hours	3/231/0
LU	Latch-up	(per JESD78)	3/18/0
TC	Temperature Cycle, -55/125C	700 Cycles	3/231/0

- Qual Device BQ25910YFFR is qualified at LEVEL 1-260C

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

- The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

- The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours

- The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: <http://www.ti.com/>

Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green

For questions regarding this notice, e-mails can be sent to the contacts shown below or your local Field Sales Representative.

Location	E-Mail
USA	PCNAmericasContact@list.ti.com
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Asia Pacific	PCNAsiaContact@list.ti.com
WW PCN Team	PCN_ww_admin_team@list.ti.com